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Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	110592
Number of I/O	235
Number of Gates	600000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	484-BGA
Supplier Device Package	484-FPBGA (23x23)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a3p600-fgg484i

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong



0-I/O is set to drive out logic Low

Last Known State – I/O is set to the last value that was driven out prior to entering the programming mode, and then held at that value during programming

Z -Tristate: I/O is tristated

rom file Save to file			Show BSR De
Port Name	Macro Cell	Pin Number	1/O State (Output Only)
BIST	ADLIB:INBUF	T2	1
BYPASS_IO	ADLIB:INBUF	K1	1
CLK	ADLIB:INBUF	B1	1
ENOUT	ADLIB:INBUF	J16	1
LED	ADLIB:OUTBUF	M3	0
MONITOR(0)	ADLIB:OUTBUF	B5	0
MONITOR[1]	ADLIB:OUTBUF	C7	Z
MONITOR[2]	ADLIB:OUTBUF	D9	Z
MONITOR(3)	ADLIB:OUTBUF	D7	Z
MONITOR[4]	ADLIB:OUTBUF	A11	Z
OEa	ADLIB:INBUF	E4	Z
ОЕЬ	ADLIB:INBUF	F1	Z
OSC_EN	ADLIB:INBUF	K3	Z
PAD[10]	ADLIB:BIBUF_LVCMOS33U	M8	Z
PAD[11]	ADLIB:BIBUF_LVCMOS33D	R7	Z
PAD[12]	ADLIB:BIBUF_LVCMOS33U	D11	Z
PAD[13]	ADLIB:BIBUF_LVCMOS33D	C12	Z
PAD[14]	ADLIB:BIBUF_LVCMOS33U	R6	Z
1			-

Figure 1-4 • I/O States During Programming Window

- 6. Click OK to return to the FlashPoint Programming File Generator window.
- Note: I/O States During programming are saved to the ADB and resulting programming files after completing programming file generation.



Table 2-11 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings¹ Applicable to Advanced I/O Banks

	C _{LOAD} (pF)	VCCI (V)	Static Power PDC3 (mW) ²	Dynamic Power PAC10 (µW/MHz) ³
Single-Ended		•		-
3.3 V LVTTL / 3.3 V LVCMOS	35	3.3	-	468.67
3.3 V LVCMOS Wide Range ⁴	35	3.3	-	468.67
2.5 V LVCMOS	35	2.5	-	267.48
1.8 V LVCMOS	35	1.8	-	149.46
1.5 V LVCMOS (JESD8-11)	35	1.5	-	103.12
3.3 V PCI	10	3.3	-	201.02
3.3 V PCI-X	10	3.3	-	201.02
Differential		•		•
LVDS	_	2.5	7.74	88.92
LVPECL	_	3.3	19.54	166.52

Notes:

1. Dynamic power consumption is given for standard load and software default drive strength and output slew.

2. PDC3 is the static power (where applicable) measured on VCCI.

3. PAC10 is the total dynamic power measured on VCC and VCCI.

4. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.

Table 2-12 • Summary of I/O Output Buffer Power (Per Pin) – Default I/O Software Settings¹ Applicable to Standard Plus I/O Banks

	C _{LOAD} (pF)	VCCI (V)	Static Power PDC3 (mW) ²	Dynamic Power PAC10 (µW/MHz) ³
Single-Ended				•
3.3 V LVTTL / 3.3 V LVCMOS	35	3.3	-	452.67
3.3 V LVCMOS Wide Range ⁴	35	3.3	-	452.67
2.5 V LVCMOS	35	2.5	-	258.32
1.8 V LVCMOS	35	1.8	-	133.59
1.5 V LVCMOS (JESD8-11)	35	1.5	-	92.84
3.3 V PCI	10	3.3	-	184.92
3.3 V PCI-X	10	3.3	_	184.92

Notes:

1. Dynamic power consumption is given for standard load and software default drive strength and output slew.

2. P_{DC3} is the static power (where applicable) measured on VMV.

3. P_{AC10} is the total dynamic power measured on VCC and VMV.

4. All LVCMOS 3.3 V software macros support LVCMOS 3.3 V wide range as specified in the JESD8-B specification.



User I/O Characteristics

Timing Model







Single-Ended I/O Characteristics

3.3 V LVTTL / 3.3 V LVCMOS

Low-Voltage Transistor–Transistor Logic (LVTTL) is a general-purpose standard (EIA/JESD) for 3.3 V applications. It uses an LVTTL input buffer and push-pull output buffer.

Table 2-37 • Minimum and Maximum DC Input and Output Levels Applicable to Advanced I/O Banks

3.3 V LVTTL / 3.3 V LVCMOS	v	ΊL	v	ΊH	VOL	VOH	IOL	юн	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min V	Max V	Min V	Max V	Max V	Min V	mA	mA	Max mA ³	Max mA ³	μA ⁴	μA ⁴
2 mA	-0.3	0.8	2	3.6	0.4	2.4	2	2	27	25	10	10
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
6 mA	-0.3	0.8	2	3.6	0.4	2.4	6	6	54	51	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10
12 mA	-0.3	0.8	2	3.6	0.4	2.4	12	12	109	103	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	127	132	10	10
24 mA	-0.3	0.8	2	3.6	0.4	2.4	24	24	181	268	10	10

Notes:

1. IIL is the input leakage current per I/O pin over recommended operation conditions where -0.3 V < VIN < VIL.

2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges

- 3. Currents are measured at 100°C junction temperature and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.

Table 2-38 • Minimum and Maximum DC Input and Output Levels Applicable to Standard Plus I/O Banks

3.3 V LVTTL / 3.3 V LVCMOS	3.3 V LVTTL / 3.3 V LVCMOS VIL		V	ΊH	VOL	VOH	IOL	юн	IOSL	IOSH	IIL ¹	IIH ²
Drive Strength	Min V	Max V	Min V	Max V	Max V	Min V	mA	mA	Max mA ³	Max mA ³	μA ⁴	μA ⁴
2 mA	-0.3	0.8	2	3.6	0.4	2.4	2	2	27	25	10	10
4 mA	-0.3	0.8	2	3.6	0.4	2.4	4	4	27	25	10	10
6 mA	-0.3	0.8	2	3.6	0.4	2.4	6	6	54	51	10	10
8 mA	-0.3	0.8	2	3.6	0.4	2.4	8	8	54	51	10	10
12 mA	-0.3	0.8	2	3.6	0.4	2.4	12	12	109	103	10	10
16 mA	-0.3	0.8	2	3.6	0.4	2.4	16	16	109	103	10	10

Notes:

1. IIL is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.

2. IIH is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges

- 3. Currents are measured at 100°C junction temperature and maximum voltage.
- 4. Currents are measured at 85°C junction temperature.
- 5. Software default selection highlighted in gray.



	Applica	Die to St	anuaru			.9							
Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	t _{ZLS}	t _{zHS}	Units
2 mA	Std.	0.66	9.68	0.04	1.00	0.43	9.86	8.42	2.28	2.21	12.09	10.66	ns
	-1	0.56	8.23	0.04	0.85	0.36	8.39	7.17	1.94	1.88	10.29	9.07	ns
	-2	0.49	7.23	0.03	0.75	0.32	7.36	6.29	1.70	1.65	9.03	7.96	ns
4 mA	Std.	0.66	9.68	0.04	1.00	0.43	9.86	8.42	2.28	2.21	12.09	10.66	ns
	-1	0.56	8.23	0.04	0.85	0.36	8.39	7.17	1.94	1.88	10.29	9.07	ns
	-2	0.49	7.23	0.03	0.75	0.32	7.36	6.29	1.70	1.65	9.03	7.96	ns
6 mA	Std.	0.66	6.70	0.04	1.00	0.43	6.82	5.89	2.58	2.74	9.06	8.12	ns
	-1	0.56	5.70	0.04	0.85	0.36	5.80	5.01	2.20	2.33	7.71	6.91	ns
	-2	0.49	5.00	0.03	0.75	0.32	5.10	4.40	1.93	2.05	6.76	6.06	ns
8 mA	Std.	0.66	6.70	0.04	1.00	0.43	6.82	5.89	2.58	2.74	9.06	8.12	ns
	-1	0.56	5.70	0.04	0.85	0.36	5.80	5.01	2.20	2.33	7.71	6.91	ns
	-2	0.49	5.00	0.03	0.75	0.32	5.10	4.40	1.93	2.05	6.76	6.06	ns
12 mA	Std.	0.66	5.05	0.04	1.00	0.43	5.14	4.51	2.79	3.08	7.38	6.75	ns
	-1	0.56	4.29	0.04	0.85	0.36	4.37	3.84	2.38	2.62	6.28	5.74	ns
	-2	0.49	3.77	0.03	0.75	0.32	3.84	3.37	2.09	2.30	5.51	5.04	ns
16 mA	Std.	0.66	5.05	0.04	1.00	0.43	5.14	4.51	2.79	3.08	7.38	6.75	ns
	-1	0.56	4.29	0.04	0.85	0.36	4.37	3.84	2.38	2.62	6.28	5.74	ns
	-2	0.49	3.77	0.03	0.75	0.32	3.84	3.37	2.09	2.30	5.51	5.04	ns

Table 2-44 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew

Commercial-Case Conditions: $T_J = 70^{\circ}$ C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Standard Plus I/O Banks

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-45 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 3.0 V Applicable to Standard I/O Banks

Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	Units
2 mA	Std.	0.66	7.07	0.04	1.00	0.43	7.20	6.23	2.07	2.15	ns
	–1	0.56	6.01	0.04	0.85	0.36	6.12	5.30	1.76	1.83	ns
	-2	0.49	5.28	0.03	0.75	0.32	5.37	4.65	1.55	1.60	ns
4 mA	Std.	0.66	7.07	0.04	1.00	0.43	7.20	6.23	2.07	2.15	ns
	–1	0.56	6.01	0.04	0.85	0.36	6.12	5.30	1.76	1.83	ns
	-2	0.49	5.28	0.03	0.75	0.32	5.37	4.65	1.55	1.60	ns
6 mA	Std.	0.66	4.41	0.04	1.00	0.43	4.49	3.75	2.39	2.69	ns
	–1	0.56	3.75	0.04	0.85	0.36	3.82	3.19	2.04	2.29	ns
	-2	0.49	3.29	0.03	0.75	0.32	3.36	2.80	1.79	2.01	ns
8 mA	Std.	0.66	4.41	0.04	1.00	0.43	4.49	3.75	2.39	2.69	ns
	-1	0.56	3.75	0.04	0.85	0.36	3.82	3.19	2.04	2.29	ns



Table 2-71 • 1.8 V LVCMOS Low Slew

Commercial-Case Conditions: T_J = 70°C, Worst-Case VCC = 1.425 V, Worst-Case VCCI = 1.7 V Applicable to Advanced I/O Banks

		r	r			r							
Drive Strength	Speed Grade	t _{DOUT}	t _{DP}	t _{DIN}	t _{PY}	t _{EOUT}	t _{ZL}	t _{zH}	t _{LZ}	t _{HZ}	t _{ZLS}	t _{zHS}	Units
2 mA	Std.	0.66	15.53	0.04	1.22	0.43	14.11	15.53	2.78	1.60	16.35	17.77	ns
	-1	0.56	13.21	0.04	1.04	0.36	12.01	13.21	2.36	1.36	13.91	15.11	ns
	-2	0.49	11.60	0.03	0.91	0.32	10.54	11.60	2.07	1.19	12.21	13.27	ns
4 mA	Std.	0.66	10.48	0.04	1.22	0.43	10.41	10.48	3.23	2.73	12.65	12.71	ns
	-1	0.56	8.91	0.04	1.04	0.36	8.86	8.91	2.75	2.33	10.76	10.81	ns
	-2	0.49	7.82	0.03	0.91	0.32	7.77	7.82	2.41	2.04	9.44	9.49	ns
6 mA	Std.	0.66	8.05	0.04	1.22	0.43	8.20	7.84	3.54	3.27	10.43	10.08	ns
	-1	0.56	6.85	0.04	1.04	0.36	6.97	6.67	3.01	2.78	8.88	8.57	ns
	-2	0.49	6.01	0.03	0.91	0.32	6.12	5.86	2.64	2.44	7.79	7.53	ns
8 mA	Std.	0.66	7.50	0.04	1.22	0.43	7.64	7.30	3.61	3.41	9.88	9.53	ns
	-1	0.56	6.38	0.04	1.04	0.36	6.50	6.21	3.07	2.90	8.40	8.11	ns
	-2	0.49	5.60	0.03	0.91	0.32	5.71	5.45	2.69	2.55	7.38	7.12	ns
12 mA	Std.	0.66	7.29	0.04	1.22	0.43	7.23	7.29	3.71	3.95	9.47	9.53	ns
	-1	0.56	6.20	0.04	1.04	0.36	6.15	6.20	3.15	3.36	8.06	8.11	ns
	-2	0.49	5.45	0.03	0.91	0.32	5.40	5.45	2.77	2.95	7.07	7.12	ns
16 mA	Std.	0.66	7.29	0.04	1.22	0.43	7.23	7.29	3.71	3.95	9.47	9.53	ns
	-1	0.56	6.20	0.04	1.04	0.36	6.15	6.20	3.15	3.36	8.06	8.11	ns
	-2	0.49	5.45	0.03	0.91	0.32	5.40	5.45	2.77	2.95	7.07	7.12	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.



B-LVDS/M-LVDS

Bus LVDS (B-LVDS) and Multipoint LVDS (M-LVDS) specifications extend the existing LVDS standard to highperformance multipoint bus applications. Multidrop and multipoint bus configurations may contain any combination of drivers, receivers, and transceivers. Microsemi LVDS drivers provide the higher drive current required by B-LVDS and M-LVDS to accommodate the loading. The drivers require series terminations for better signal quality and to control voltage swing. Termination is also required at both ends of the bus since the driver can be located anywhere on the bus. These configurations can be implemented using the TRIBUF_LVDS and BIBUF_LVDS macros along with appropriate terminations. Multipoint designs using Microsemi LVDS macros can achieve up to 200 MHz with a maximum of 20 loads. A sample application is given in Figure 2-13. The input and output buffer delays are available in the LVDS section in Table 2-92.

Example: For a bus consisting of 20 equidistant loads, the following terminations provide the required differential voltage, in worst-case Industrial operating conditions, at the farthest receiver: $R_S = 60 \Omega$ and $R_T = 70 \Omega$, given $Z_0 = 50 \Omega$ (2") and $Z_{stub} = 50 \Omega$ (~1.5").





LVPECL

Low-Voltage Positive Emitter-Coupled Logic (LVPECL) is another differential I/O standard. It requires that one data bit be carried through two signal lines. Like LVDS, two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-14. The building blocks of the LVPECL transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVDS implementation because the output standard specifications are different.











Figure 2-16 • Timing Model of the Registered I/O Buffers with Synchronous Enable and Asynchronous Clear



VersaTile Characteristics

VersaTile Specifications as a Combinatorial Module

The ProASIC3 library offers all combinations of LUT-3 combinatorial functions. In this section, timing characteristics are presented for a sample of the library. For more details, refer to the *Fusion, IGLOO®/e, and ProASIC3/E Macro Library Guide*.



Figure 2-24 • Sample of Combinatorial Cells



mode is not used in the design, the FF pin is available as a regular I/O. For IGLOOe, ProASIC3EL, and RT ProASIC3 only, the FF pin can be configured as a Schmitt trigger input.

When Flash*Freeze mode is used, the FF pin must not be left floating to avoid accidentally entering Flash*Freeze mode. While in Flash*Freeze mode, the Flash*Freeze pin should be constantly asserted.

The Flash*Freeze pin can be used with any single-ended I/O standard supported by the I/O bank in which the pin is located, and input signal levels compatible with the I/O standard selected. The FF pin should be treated as a sensitive asynchronous signal. When defining pin placement and board layout, simultaneously switching outputs (SSOs) and their effects on sensitive asynchronous pins must be considered.

Unused FF or I/O pins are tristated with weak pull-up. This default configuration applies to both Flash*Freeze mode and normal operation mode. No user intervention is required.

JTAG Pins

Low power flash devices have a separate bank for the dedicated JTAG pins. The JTAG pins can be run at any voltage from 1.5 V to 3.3 V (nominal). VCC must also be powered for the JTAG state machine to operate, even if the device is in bypass mode; VJTAG alone is insufficient. Both VJTAG and VCC to the part must be supplied to allow JTAG signals to transition the device. Isolating the JTAG power supply in a separate I/O bank gives greater flexibility in supply selection and simplifies power supply and PCB design. If the JTAG interface is neither used nor planned for use, the VJTAG pin together with the TRST pin could be tied to GND.

TCK Test Clock

Test clock input for JTAG boundary scan, ISP, and UJTAG. The TCK pin does not have an internal pull-up/-down resistor. If JTAG is not used, Microsemi recommends tying off TCK to GND through a resistor placed close to the FPGA pin. This prevents JTAG operation in case TMS enters an undesired state.

Note that to operate at all VJTAG voltages, 500 Ω to 1 k Ω will satisfy the requirements. Refer to Table 1 for more information.

VJTAG	Tie-Off Resistance
3.3 V	200 Ω –1 kΩ
2.5 V	200 Ω –1 kΩ
1.8 V	500 Ω –1 kΩ
1.5 V	500 Ω –1 kΩ

Table 1 • Recommended Tie-Off Values for the TCK and TRST Pins

Notes:

- 1. Equivalent parallel resistance if more than one device is on the JTAG chain
- 2. The TCK pin can be pulled up/down.
- 3. The TRST pin is pulled down.

TDI Test Data Input

Serial input for JTAG boundary scan, ISP, and UJTAG usage. There is an internal weak pull-up resistor on the TDI pin.

TDO Test Data Output

Serial output for JTAG boundary scan, ISP, and UJTAG usage.

TMS Test Mode Select

The TMS pin controls the use of the IEEE 1532 boundary scan pins (TCK, TDI, TDO, TRST). There is an internal weak pull-up resistor on the TMS pin.

TRST Boundary Scan Reset Pin

The TRST pin functions as an active low input to asynchronously initialize (or reset) the boundary scan circuitry. There is an internal weak pull-up resistor on the TRST pin. If JTAG is not used, an external pull-down resistor could be included to ensure the test access port (TAP) is held in reset mode. The resistor values must be chosen from Table 1 and must satisfy the parallel resistance value requirement. The values in Table 1 correspond to the resistor recommended when a single device is used, and the equivalent parallel resistor when multiple devices are connected via a JTAG chain.



TQ144							
Pin Number	A3P060 Function						
109	NC						
110	NC						
111	GBA1/IO24RSB0						
112	GBA0/IO23RSB0						
113	GBB1/IO22RSB0						
114	GBB0/IO21RSB0						
115	GBC1/IO20RSB0						
116	GBC0/IO19RSB0						
117	VCCIB0						
118	GND						
119	VCC						
120	IO18RSB0						
121	IO17RSB0						
122	IO16RSB0						
123	IO15RSB0						
124	IO14RSB0						
125	IO13RSB0						
126	IO12RSB0						
127	IO11RSB0						
128	NC						
129	IO10RSB0						
130	IO09RSB0						
131	IO08RSB0						
132	GAC1/IO07RSB0						
133	GAC0/IO06RSB0						
134	NC						
135	GND						
136	NC						
137	GAB1/IO05RSB0						
138	GAB0/IO04RSB0						
139	GAA1/IO03RSB0						
140	GAA0/IO02RSB0						
141	IO01RSB0						
142	IO00RSB0						
143	GNDQ						
144	VMV0						



	PQ208		PQ208		PQ208
Pin Number	A3P1000 Function	Pin Number	A3P1000 Function	Pin Number	A3P1000 Function
1	GND	37	IO199PDB3	73	IO162RSB2
2	GAA2/IO225PDB3	38	IO199NDB3	74	IO160RSB2
3	IO225NDB3	39	IO197PSB3	75	IO158RSB2
4	GAB2/IO224PDB3	40	VCCIB3	76	IO156RSB2
5	IO224NDB3	41	GND	77	IO154RSB2
6	GAC2/IO223PDB3	42	IO191PDB3	78	IO152RSB2
7	IO223NDB3	43	IO191NDB3	79	IO150RSB2
8	IO222PDB3	44	GEC1/IO190PDB3	80	IO148RSB2
9	IO222NDB3	45	GEC0/IO190NDB3	81	GND
10	IO220PDB3	46	GEB1/IO189PDB3	82	IO143RSB2
11	IO220NDB3	47	GEB0/IO189NDB3	83	IO141RSB2
12	IO218PDB3	48	GEA1/IO188PDB3	84	IO139RSB2
13	IO218NDB3	49	GEA0/IO188NDB3	85	IO137RSB2
14	IO216PDB3	50	VMV3	86	IO135RSB2
15	IO216NDB3	51	GNDQ	87	IO133RSB2
16	VCC	52	GND	88	VCC
17	GND	53	VMV2	89	VCCIB2
18	VCCIB3	54	GEA2/IO187RSB2	90	IO128RSB2
19	IO212PDB3	55	GEB2/IO186RSB2	91	IO126RSB2
20	IO212NDB3	56	GEC2/IO185RSB2	92	IO124RSB2
21	GFC1/IO209PDB3	57	IO184RSB2	93	IO122RSB2
22	GFC0/IO209NDB3	58	IO183RSB2	94	IO120RSB2
23	GFB1/IO208PDB3	59	IO182RSB2	95	IO118RSB2
24	GFB0/IO208NDB3	60	IO181RSB2	96	GDC2/IO116RSB2
25	VCOMPLF	61	IO180RSB2	97	GND
26	GFA0/IO207NPB3	62	VCCIB2	98	GDB2/IO115RSB2
27	VCCPLF	63	IO178RSB2	99	GDA2/IO114RSB2
28	GFA1/IO207PPB3	64	IO176RSB2	100	GNDQ
29	GND	65	GND	101	TCK
30	GFA2/IO206PDB3	66	IO174RSB2	102	TDI
31	IO206NDB3	67	IO172RSB2	103	TMS
32	GFB2/IO205PDB3	68	IO170RSB2	104	VMV2
33	IO205NDB3	69	IO168RSB2	105	GND
34	GFC2/IO204PDB3	70	IO166RSB2	106	VPUMP
35	IO204NDB3	71	VCC	107	GNDQ
36	VCC	72	VCCIB2	108	TDO

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Package Pin Assignments

FG144		F	G144	FG144	
Pin Number	A3P250 Function	Pin Number	A3P250 Function	Pin Number	A3P250 Function
A1	GNDQ	D1	IO112NDB3	G1	GFA1/IO108PPB3
A2	VMV0	D2	IO112PDB3	G2	GND
A3	GAB0/IO02RSB0	D3	IO116VDB3	G3	VCCPLF
A4	GAB1/IO03RSB0	D4	GAA2/IO118UPB3	G4	GFA0/IO108NPB3
A5	IO16RSB0	D5	GAC0/IO04RSB0	G5	GND
A6	GND	D6	GAC1/IO05RSB0	G6	GND
A7	IO29RSB0	D7	GBC0/IO35RSB0	G7	GND
A8	VCC	D8	GBC1/IO36RSB0	G8	GDC1/IO58UPB1
A9	IO33RSB0	D9	GBB2/IO42PDB1	G9	IO53NDB1
A10	GBA0/IO39RSB0	D10	IO42NDB1	G10	GCC2/IO53PDB1
A11	GBA1/IO40RSB0	D11	IO43NPB1	G11	IO52NDB1
A12	GNDQ	D12	GCB1/IO49PPB1	G12	GCB2/IO52PDB1
B1	GAB2/IO117UDB3	E1	VCC	H1	VCC
B2	GND	E2	GFC0/IO110NDB3	H2	GFB2/IO106PDB3
B3	GAA0/IO00RSB0	E3	GFC1/IO110PDB3	H3	GFC2/IO105PSB3
B4	GAA1/IO01RSB0	E4	VCCIB3	H4	GEC1/IO100PDB3
B5	IO14RSB0	E5	IO118VPB3	H5	VCC
B6	IO19RSB0	E6	VCCIB0	H6	IO79RSB2
B7	IO22RSB0	E7	VCCIB0	H7	IO65RSB2
B8	IO30RSB0	E8	GCC1/IO48PDB1	H8	GDB2/IO62RSB2
B9	GBB0/IO37RSB0	E9	VCCIB1	H9	GDC0/IO58VPB1
B10	GBB1/IO38RSB0	E10	VCC	H10	VCCIB1
B11	GND	E11	GCA0/IO50NDB1	H11	IO54PSB1
B12	VMV1	E12	IO51NDB1	H12	VCC
C1	IO117VDB3	F1	GFB0/IO109NPB3	J1	GEB1/IO99PDB3
C2	GFA2/IO107PPB3	F2	VCOMPLF	J2	IO106NDB3
C3	GAC2/IO116UDB3	F3	GFB1/IO109PPB3	J3	VCCIB3
C4	VCC	F4	IO107NPB3	J4	GEC0/IO100NDB3
C5	IO12RSB0	F5	GND	J5	IO88RSB2
C6	IO17RSB0	F6	GND	J6	IO81RSB2
C7	IO24RSB0	F7	GND	J7	VCC
C8	IO31RSB0	F8	GCC0/IO48NDB1	J8	ТСК
C9	IO34RSB0	F9	GCB0/IO49NPB1	J9	GDA2/IO61RSB2
C10	GBA2/IO41PDB1	F10	GND	J10	TDO
C11	IO41NDB1	F11	GCA1/IO50PDB1	J11	GDA1/IO60UDB1
C12	GBC2/IO43PPB1	F12	GCA2/IO51PDB1	J12	GDB1/IO59UDB1



FG256				
Pin Number	A3P600 Function			
P9	IO107RSB2			
P10	IO104RSB2			
P11	IO97RSB2			
P12	VMV1			
P13	ТСК			
P14	VPUMP			
P15	TRST			
P16	GDA0/IO88NDB1			
R1	GEA1/IO144PDB3			
R2	GEA0/IO144NDB3			
R3	IO139RSB2			
R4	GEC2/IO141RSB2			
R5	IO132RSB2			
R6	IO127RSB2			
R7	IO121RSB2			
R8	IO114RSB2			
R9	IO109RSB2			
R10	IO105RSB2			
R11	IO98RSB2			
R12	IO96RSB2			
R13	GDB2/IO90RSB2			
R14	TDI			
R15	GNDQ			
R16	TDO			
T1	GND			
T2	IO137RSB2			
Т3	GEB2/IO142RSB2			
T4	IO134RSB2			
T5	IO125RSB2			
Т6	IO123RSB2			
T7	IO118RSB2			
Т8	IO115RSB2			
Т9	IO111RSB2			
T10	IO106RSB2			
T11	IO102RSB2			
T12	GDC2/IO91RSB2			

FG256			
Pin Number	A3P600 Function		
T13	IO93RSB2		
T14	GDA2/IO89RSB2		
T15	TMS		
T16	GND		



Package Pin Assignments

	FG484		FG484	FG484	
Pin Number	A3P600 Function	Pin Number	A3P600 Function	Pin Number	A3P600 Function
E21	NC	G13	IO40RSB0	J5	IO168NPB3
E22	NC	G14	IO45RSB0	J6	IO167PPB3
F1	NC	G15	GNDQ	J7	IO169PDB3
F2	NC	G16	IO50RSB0	J8	VCCIB3
F3	NC	G17	GBB2/IO61PPB1	J9	GND
F4	IO173NDB3	G18	IO53RSB0	J10	VCC
F5	IO174NDB3	G19	IO63NDB1	J11	VCC
F6	VMV3	G20	NC	J12	VCC
F7	IO07RSB0	G21	NC	J13	VCC
F8	GAC0/IO04RSB0	G22	NC	J14	GND
F9	GAC1/IO05RSB0	H1	NC	J15	VCCIB1
F10	IO20RSB0	H2	NC	J16	IO62NDB1
F11	IO24RSB0	H3	VCC	J17	IO64NPB1
F12	IO33RSB0	H4	IO166PDB3	J18	IO65PPB1
F13	IO39RSB0	H5	IO167NPB3	J19	IO66NDB1
F14	IO44RSB0	H6	IO172NDB3	J20	NC
F15	GBC0/IO54RSB0	H7	IO169NDB3	J21	IO68PDB1
F16	IO51RSB0	H8	VMV0	J22	IO68NDB1
F17	VMV0	H9	VCCIB0	K1	IO157PDB3
F18	IO61NPB1	H10	VCCIB0	K2	IO157NDB3
F19	IO63PDB1	H11	IO25RSB0	К3	NC
F20	NC	H12	IO31RSB0	K4	IO165NDB3
F21	NC	H13	VCCIB0	K5	IO165PDB3
F22	NC	H14	VCCIB0	K6	IO168PPB3
G1	IO170NDB3	H15	VMV1	K7	GFC1/IO164PPB3
G2	IO170PDB3	H16	GBC2/IO62PDB1	K8	VCCIB3
G3	NC	H17	IO67PPB1	К9	VCC
G4	IO171NDB3	H18	IO64PPB1	K10	GND
G5	IO171PDB3	H19	IO66PDB1	K11	GND
G6	GAC2/IO172PDB3	H20	VCC	K12	GND
G7	IO06RSB0	H21	NC	K13	GND
G8	GNDQ	H22	NC	K14	VCC
G9	IO10RSB0	J1	NC	K15	VCCIB1
G10	IO19RSB0	J2	NC	K16	GCC1/IO69PPB1
G11	IO26RSB0	J3	NC	K17	IO65NPB1
G12	IO30RSB0	J4	IO166NDB3	K18	IO75PDB1



	FG484		FG484	FG484	
Pin Number	A3P600 Function	Pin Number	A3P600 Function	Pin Number	A3P600 Function
K19	IO75NDB1	M11	GND	P3	IO153NDB3
K20	NC	M12	GND	P4	IO159NDB3
K21	IO76NDB1	M13	GND	P5	IO156NPB3
K22	IO76PDB1	M14	VCC	P6	IO151PPB3
L1	NC	M15	GCB2/IO73PPB1	P7	IO158PPB3
L2	IO155PDB3	M16	GCA1/IO71PPB1	P8	VCCIB3
L3	NC	M17	GCC2/IO74PPB1	P9	GND
L4	GFB0/IO163NPB3	M18	IO80PPB1	P10	VCC
L5	GFA0/IO162NDB3	M19	GCA2/IO72PDB1	P11	VCC
L6	GFB1/IO163PPB3	M20	IO79PPB1	P12	VCC
L7	VCOMPLF	M21	IO78PPB1	P13	VCC
L8	GFC0/IO164NPB3	M22	NC	P14	GND
L9	VCC	N1	IO154NDB3	P15	VCCIB1
L10	GND	N2	IO154PDB3	P16	GDB0/IO87NPB1
L11	GND	N3	NC	P17	IO85NDB1
L12	GND	N4	GFC2/IO159PDB3	P18	IO85PDB1
L13	GND	N5	IO161NPB3	P19	IO84PDB1
L14	VCC	N6	IO156PPB3	P20	NC
L15	GCC0/IO69NPB1	N7	IO129RSB2	P21	IO81PDB1
L16	GCB1/IO70PPB1	N8	VCCIB3	P22	NC
L17	GCA0/IO71NPB1	N9	VCC	R1	NC
L18	IO67NPB1	N10	GND	R2	NC
L19	GCB0/IO70NPB1	N11	GND	R3	VCC
L20	IO77PDB1	N12	GND	R4	IO150PDB3
L21	IO77NDB1	N13	GND	R5	IO151NPB3
L22	IO78NPB1	N14	VCC	R6	IO147NPB3
M1	NC	N15	VCCIB1	R7	GEC0/IO146NPB3
M2	IO155NDB3	N16	IO73NPB1	R8	VMV3
M3	IO158NPB3	N17	IO80NPB1	R9	VCCIB2
M4	GFA2/IO161PPB3	N18	IO74NPB1	R10	VCCIB2
M5	GFA1/IO162PDB3	N19	IO72NDB1	R11	IO117RSB2
M6	VCCPLF	N20	NC	R12	IO110RSB2
M7	IO160NDB3	N21	IO79NPB1	R13	VCCIB2
M8	GFB2/IO160PDB3	N22	NC	R14	VCCIB2
M9	VCC	P1	NC	R15	VMV2
M10	GND	P2	IO153PDB3	R16	IO94RSB2

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Package Pin Assignments

	FG484		FG484		FG484	
Pin Number	A3P1000 Function	Pin Number	A3P1000 Function	Pin Number	A3P1000 Function	
K19	IO88NDB1	M11	GND	P3	IO199NDB3	
K20	IO94NPB1	M12	GND	P4	IO202NDB3	
K21	IO98NDB1	M13	GND	P5	IO202PDB3	
K22	IO98PDB1	M14	VCC	P6	IO196PPB3	
L1	NC	M15	GCB2/IO95PPB1	P7	IO193PPB3	
L2	IO200PDB3	M16	GCA1/IO93PPB1	P8	VCCIB3	
L3	IO210NPB3	M17	GCC2/IO96PPB1	P9	GND	
L4	GFB0/IO208NPB3	M18	IO100PPB1	P10	VCC	
L5	GFA0/IO207NDB3	M19	GCA2/IO94PPB1	P11	VCC	
L6	GFB1/IO208PPB3	M20	IO101PPB1	P12	VCC	
L7	VCOMPLF	M21	IO99PPB1	P13	VCC	
L8	GFC0/IO209NPB3	M22	NC	P14	GND	
L9	VCC	N1	IO201NDB3	P15	VCCIB1	
L10	GND	N2	IO201PDB3	P16	GDB0/IO112NPB1	
L11	GND	N3	NC	P17	IO106NDB1	
L12	GND	N4	GFC2/IO204PDB3	P18	IO106PDB1	
L13	GND	N5	IO204NDB3	P19	IO107PDB1	
L14	VCC	N6	IO203NDB3	P20	NC	
L15	GCC0/IO91NPB1	N7	IO203PDB3	P21	IO104PDB1	
L16	GCB1/IO92PPB1	N8	VCCIB3	P22	IO103NDB1	
L17	GCA0/IO93NPB1	N9	VCC	R1	NC	
L18	IO96NPB1	N10	GND	R2	IO197PPB3	
L19	GCB0/IO92NPB1	N11	GND	R3	VCC	
L20	IO97PDB1	N12	GND	R4	IO197NPB3	
L21	IO97NDB1	N13	GND	R5	IO196NPB3	
L22	IO99NPB1	N14	VCC	R6	IO193NPB3	
M1	NC	N15	VCCIB1	R7	GEC0/IO190NPB3	
M2	IO200NDB3	N16	IO95NPB1	R8	VMV3	
M3	IO206NDB3	N17	IO100NPB1	R9	VCCIB2	
M4	GFA2/IO206PDB3	N18	IO102NDB1	R10	VCCIB2	
M5	GFA1/IO207PDB3	N19	IO102PDB1	R11	IO147RSB2	
M6	VCCPLF	N20	NC	R12	IO136RSB2	
M7	IO205NDB3	N21	IO101NPB1	R13	VCCIB2	
M8	GFB2/IO205PDB3	N22	IO103PDB1	R14	VCCIB2	
M9	VCC	P1	NC	R15	VMV2	
M10	GND	P2	IO199PDB3	R16	IO110NDB1	



5 – Datasheet Information

List of Changes

The following table lists critical changes that were made in each version of the ProASIC3 datasheet.

Revision	Changes	Page
Revision 18 (March 2016)	Updated 3.3 V DC supply voltage's maximum Commercial and Industrial values from 3.3 V to 3.6 V in Table 2-2 (SAR 72693).	2-2
	Added reference of Package Mechanical Drawings document in all package pin assignment notes (76833).	NA
Revision 17	Removed PQFP embedded heat spreader info. from Table 2-5 (SAR 52320).	2-6
(June 2015)	Updated "VCCIBx I/O Supply Voltage" (SAR 43323).	3-1
Revision 16 (December 2014)	Updated "ProASIC3 Ordering Information". Interchanged the positions of Y- Security Feature and I- Application (Temperature Range) (SAR 61079). Added Note "Only devices with package size greater than or equal to 5x5 are supported".	1-IV
	Updated Table Note (2) in Table 2-3 • Flash Programming Limits – Retention, Storage and Operating Temperature so that the Table Note is not applicable for Maximum Storage Temperature T_{STG} (SAR 54297).	2-3
	Added values for Drive strength 2 mA in Table 2-41 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew, Table 2-42 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew, Table 2-43 • 3.3 V LVTTL / 3.3 V LVCMOS High Slew, and Table 2-44 • 3.3 V LVTTL / 3.3 V LVCMOS Low Slew (SAR 57184).	2-34, 2-35, 2-36, 2-37
	Added Figure 2-1 • High-Temperature Data Retention (HTR) (SAR 45466).	2-3
	Updates made to maintain the style and consistency of the document.	NA
Revision 15 (July 2014)	Added corner pad table note (3) to "QN132 – Bottom View" (SAR 47442).	4-6
	Ambient temperature removed in Table 2-2, table notes and "ProASIC3 Ordering Information" figure were modified (SAR 48343).	2-2 1-IV
	Other updates were made to maintain the style and consistency of the datasheet.	NA
Revision 14 (April 2014)	Note added for the discontinuance of QN132 package to the following tables and section: "ProASIC3 Devices", "I/Os Per Package 1", "ProASIC3 FPGAs Package Sizes Dimensions" and "QN132 – Bottom View" section (SAR 55118).	I, III, 4-6



Datasheet Information

Revision	Changes	Page
Revision 5 (Aug 2008) DC and Switching Characteristics v1.3	TJ, Maximum Junction Temperature, was changed to 100° from 110° in the "Thermal Characteristics" section and EQ 1. The calculated result of Maximum Power Allowed has thus changed to 1.463 W from 1.951 W.	2-6
	Values for the A3P015 device were added to Table 2-7 • Quiescent Supply Current Characteristics.	2-7
	Values for the A3P015 device were added to Table 2-14 • Different Components Contributing to Dynamic Power Consumption in ProASIC3 Devices. P_{AC14} was removed. Table 2-15 • Different Components Contributing to the Static Power Consumption in ProASIC3 Devices is new.	2-11, 2-12
	The "PLL Contribution—PPLL" section was updated to change the P_{PLL} formula from $P_{AC13} + P_{AC14} * F_{CLKOUT}$ to $P_{DC4} + P_{AC13} * F_{CLKOUT}$.	2-14
	Both fall and rise values were included for $t_{\mbox{DDRISUD}}$ and $t_{\mbox{DDRIHD}}$ in Table 2-102 \bullet Input DDR Propagation Delays.	2-78
	Table 2-107 • A3P015 Global Resource is new.	2-86
	The typical value for Delay Increments in Programmable Delay Blocks was changed from 160 to 200 in Table 2-115 • ProASIC3 CCC/PLL Specification.	2-90
Revision 4 (Jun 2008) DC and Switching Characteristics v1.2	Table note references were added to Table 2-2 • Recommended Operating Conditions 1, and the order of the table notes was changed.	2-2
	The title for Table 2-4 • Overshoot and Undershoot Limits 1 was modified to remove "as measured on quiet I/Os." Table note 1 was revised to remove "estimated SSO density over cycles." Table note 2 was revised to remove "refers only to overshoot/undershoot limits for simultaneous switching I/Os."	2-3
	The "Power per I/O Pin" section was updated to include 3 additional tables pertaining to input buffer power and output buffer power.	2-7
	Table 2-29 • I/O Output Buffer Maximum Resistances 1 was revised to include values for 3.3 V PCI/PCI-X.	2-27
	Table 2-90 • LVDS Minimum and Maximum DC Input and Output Levels was updated.	2-66
Revision 3 (Jun 2008) Packaging v1.3	Pin numbers were added to the "QN68 – Bottom View" package diagram. Note 2 was added below the diagram.	4-3
	The "QN132 – Bottom View" package diagram was updated to include D1 to D4. In addition, note 1 was changed from top view to bottom view, and note 2 is new.	4-6
Revision 2 (Feb 2008) Product Brief v1.0	This document was divided into two sections and given a version number, starting at v1.0. The first section of the document includes features, benefits, ordering information, and temperature and speed grade offerings. The second section is a device family overview.	N/A
	This document was updated to include A3P015 device information. QN68 is a new package that was added because it is offered in the A3P015. The following sections were updated: "Features and Benefits" "ProASIC3 Ordering Information" "Temperature Grade Offerings" "ProASIC3 Flash Family FPGAs" "A3P015 and A3P030" note	N/A
	Introduction and Overview (NA)	



Revision	Changes	Page
v2.0 (continued)	Table 3-20 • Summary of I/O Timing Characteristics—Software Default Settings (Advanced) and Table 3-21 • Summary of I/O Timing Characteristics—Software Default Settings (Standard Plus) were updated.	
	Table 3-11 • Different Components Contributing to Dynamic Power Consumptionin ProASIC3 Devices was updated.	3-9
	Table 3-24 • I/O Output Buffer Maximum Resistances1 (Advanced) and Table 3-25 • I/O Output Buffer Maximum Resistances1 (Standard Plus) were updated.	3-22 to 3-22
	Table 3-17 • Summary of Maximum and Minimum DC Input Levels Applicable to Commercial and Industrial Conditions was updated.	3-18
	Table 3-28 • I/O Short Currents IOSH/IOSL (Advanced) and Table 3-29 • I/O Short Currents IOSH/IOSL (Standard Plus) were updated.	3-24 to 3-26
	The note in Table 3-32 • I/O Input Rise Time, Fall Time, and Related I/O Reliability was updated.	3-27
	Figure 3-33 • Write Access After Write onto Same Address, Figure 3-34 • Read Access After Write onto Same Address, and Figure 3-35 • Write Access After Read onto Same Address are new.	3-82 to 3-84
	Figure 3-43 • Timing Diagram was updated.	3-96
	Ambient was deleted from the "Speed Grade and Temperature Grade Matrix".	iv
	Notes were added to the package diagrams identifying if they were top or bottom view.	N/A
	The A3P030 "132-Pin QFN" table is new.	4-2
	The A3P060 "132-Pin QFN" table is new.	4-4
	The A3P125 "132-Pin QFN" table is new.	4-6
	The A3P250 "132-Pin QFN" table is new.	4-8
	The A3P030 "100-Pin VQFP" table is new.	4-11
Advance v0.7 (January 2007)	In the "I/Os Per Package" table, the I/O numbers were added for A3P060, A3P125, and A3P250. The A3P030-VQ100 I/O was changed from 79 to 77.	ii
Advance v0.6 (April 2006)	The term flow-through was changed to pass-through.	N/A
	Table 1 was updated to include the QN132.	ii
	The "I/Os Per Package" table was updated with the QN132. The footnotes were also updated. The A3P400-FG144 I/O count was updated.	ii
	"Automotive ProASIC3 Ordering Information" was updated with the QN132.	iii
	"Temperature Grade Offerings" was updated with the QN132.	iii
	B-LVDS and M-LDVS are new I/O standards added to the datasheet.	N/A
	The term flow-through was changed to pass-through.	N/A
	Figure 2-7 • Efficient Long-Line Resources was updated.	2-7
	The footnotes in Figure 2-15 • Clock Input Sources Including CLKBUF, CLKBUF_LVDS/LVPECL, and CLKINT were updated.	2-16
	The Delay Increments in the Programmable Delay Blocks specification in Figure 2-24 • ProASIC3E CCC Options.	2-24
	The "SRAM and FIFO" section was updated.	2-21